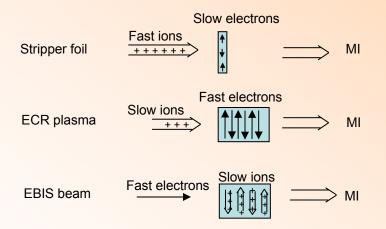
CHARGE BREEDING TECHNIQUES



RNB6
ARGONNE
22-26TH SEPTEMBER 2003





HISTORY

- * STRIPPERS AROUND SINCE EVER
- * ECRIS CB STUDIES 1993

(ISN GRENOBLE FOR PIAFE)

- * EBIS INJECTION TESTS 1994 (STOCKHOLM FOR REX)
- * REX-ISOLDE RIB 2001

OUTLINE OF TALK

- I. MOTIVATION
- 2. CB TECHNIQUES & RESULTS
 STRIPPER

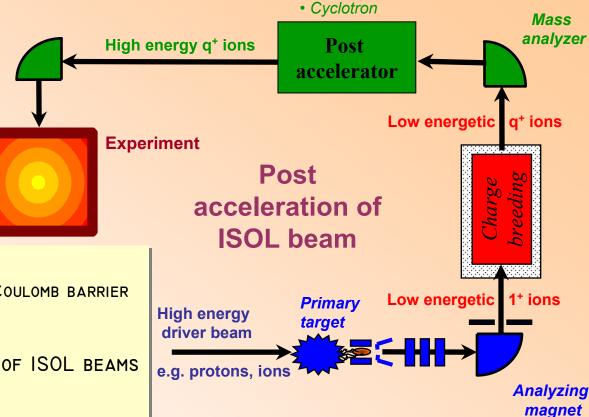
EBIS

ECRIS

- 3. FUTURE DEVELOPMENT
- 4. CONCLUSIONS

MOTIVATION

PHYSICS CASE FOR PHYSICIST TO MOTIVATE



Pulsed LINACCW LINAC

ENERGY REQUEST

- * FEW MeV/U TO REACH AND PASS COULOMB BARRIER
- * GeV FOR BETA BEAMS
- -> NEED FOR POST ACCELERATION OF ISOL BEAMS

AND

ENERGY ∝

Q IN LINAC

Q² IN CYCLOTRON

MASS-TO-CHARGE RATIO (A/Q) < 1/9







THE IDEA

Charge breed (I $^+ \rightarrow N^+$) Low-energy ions

SIMPLICITY(?)

Efficiency(?)

COMPACTNESS

(SHORTER/SIMPLER/CHEAPER LINAC)

BRUTE FORCE

HOW LONG WOULD A I+ LINAC BE?

- * W_{nucl} [MeV/u]=E_{acceleration} [V/m] * q/A [e/u] * L [m]
- * $E_{ACC} \sim 5 \text{ MV/m}$ ACCELERATION FIELD
- * LIMITED TO q/A < 1/30 OR 1/60

LIMITS



* PRICE ESTIMATE I+ ACC - PURE SCALING

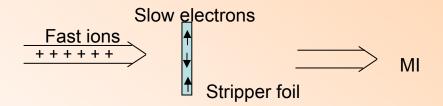
| FINAL ENERGY | MASS | LENGTH | PRICE |
|--------------|------|--------|--------|
| (MEV/U) | (A) | (M) | (MUSD) |
| 5 | 100 | 100 | 50(!) |
| 10 | 100 | 200 | 100(!) |



CERN proton LINAC2

- * Price 38 MCHF
- * Field gradient linac 1.5 2 MV/m
- * q/A=1, 50 MeV, 34 m, 3.3 m RFQ

CLASSIC CONCEPT - STRIPPING

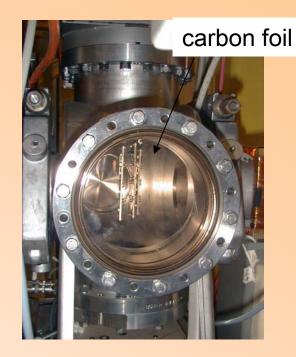


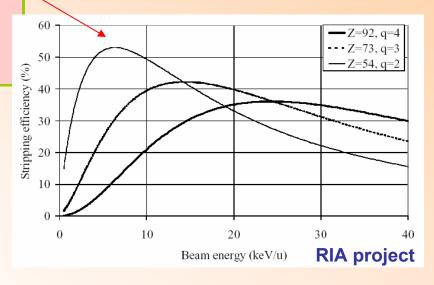
- SIMPLE METHOD AND FAST (µS ISOTOPES)
- ⊗ NEEDS PRE-ACCELERATION

IN GAS STRIPPING 8 TO 20 KEV/U IN FOIL STRIPPING ~0.5 MEV/U

- NO MACRO-BUNCHING CAPABILITY

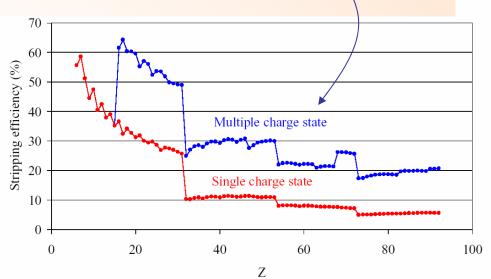
| EXAMPLE - SPES SCENARIO | | | |
|------------------------------------------|--|--|--|
| BUNCHING EFFICIENCY 65% | | | |
| GAS STRIPPING AT 8 KEV/U 40% | | | |
| STRIPPING FOIL AT 500 KEV/U 20% | | | |
| IN TOTAL (SINGLE CHARGE ACC OF 132SN) 4% | | | |

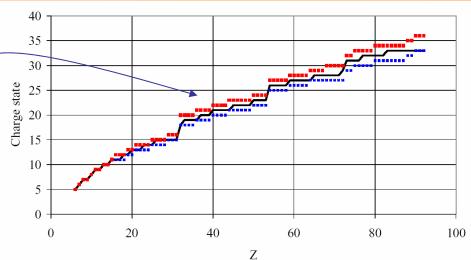




MULTI-CHARGE STATE ACCELERATION

- * ACCELERATE MULTIPLE Q AFTER THE STRIPPER
- * $\Delta q/q$ of ~20% can be accepted





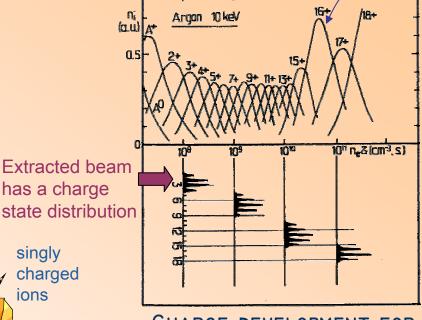
MCA and overall stripping efficiency (RIA)

RIA PROJECT

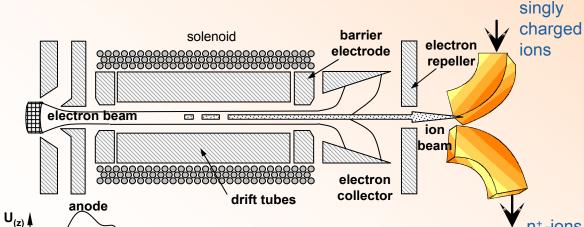
THE EBIS CHARGE BREEDER

- * PRODUCES MULTIPLY CHARGED IONS
- * IONS ARE TRAPPED IN A MAGNETO-ELECTROSTATIC TRAP
- * IONISATION BY e⁻ BOMBARDMENT FROM AN MONO-ENERGETIC e⁻ BEAM

ELECTRON BEAM ION SOURCE



CHARGE DEVELOPMENT FOR STEPWISE IONISATION



ionisation

extraction

- * ~25% IN ONE CHARGE STATE
- * MORE NEAR CLOSED SHELLS
- * VARY $T_{BREEDING} \rightarrow VARY CSD$

EBIS CHARACTERISTICS I

BREEDING CAPACITY

$$C = \frac{1.05 \cdot 10^{13} \cdot I_e L}{\sqrt{U_e}} k$$

C = number of elementary charges

I_e and U_e = e⁻ beam current and energy

k = neutralization factor

L = trap length

REAL VALUES

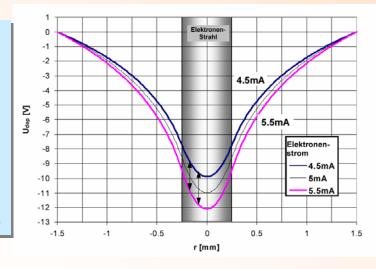
 $I_{e} = 0.5 A$

 $U_{\rm e} = 5\,000\,{\rm eV}$

L = 0.8 m

k = 50%

~3·10¹⁰ charges



CHARGE STATE

$$j_e \tau = \sum_{q=1}^{k-1} \frac{e}{\sigma_{q \to q+1}}$$

Typical ionization times (A/q<4.5) (Calculated REXEBIS values)

⁵²Ca¹²⁺ 20 ms

⁷⁰Ni¹⁶⁺ 22 ms

⁷⁸Zn¹⁸⁺ 30 ms

⁸⁶Se²⁰⁺ 40 ms

⁹⁴Kr²¹⁺ 50 ms

¹⁰²Rb²³⁺ 60 ms

¹³⁴Cd³⁰⁺ 120 ms

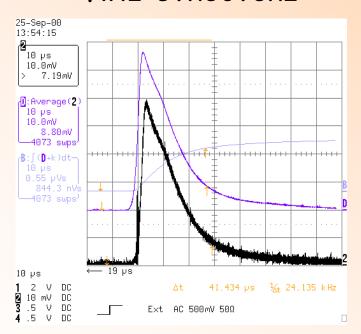
¹⁴⁴Xe³²⁺ 150 ms

¹⁴⁸Ba³³⁺ 160 ms

- **SHORT BREEDING TIME**
- © ELEMENT INDEPENDENT

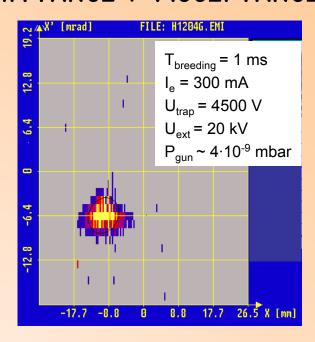
EBIS CHARACTERISTICS II

TIME STRUCTURE



- \otimes Bunched injected beam <50 μs
- © BUNCHED EXTRACTED BEAM (10 μs to several ms)
- ⊕ ENERGY SPREAD < 50*q EV
 </p>

EMITTANCE / ACCEPTANCE



- © EMITTANCE
 - $10 \pi \cdot MM \cdot MRAD (95\% AT 20 KV)$
- \odot SMALL EMITTANCE => SMALL ACCEPTANCE ~10 π·MM·MRAD (95% AT 60 KV)
- * DEPENDENT ON:

BREEDING TIME, NEUTRALIZATION ETC

PREPARATORY PENNING TRAP



Accumulation

Cooling

Ejection

PRINCIPLE

- * CONTINUOUS INJECTION
- * BUNCHING (10-20 µS BUNCH EXTRACTED)
- * Cooling (10-20 Ms)

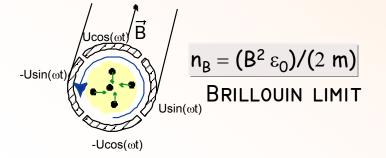
RESULTS REXTRAP

(HE), LI,...,U EFFICIENCY 45 % EMITTANCE >10 π MM MRAD @ 30 KEV

SPACE CHARGE EFFECTS WITH SIDEBAND COOLING OF MORE THAN 10⁵ IONS/PULSE
 => 10⁷ IONS/S



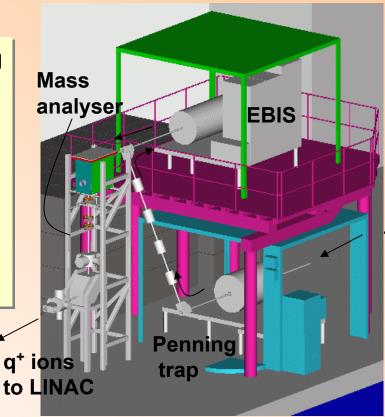
THE LARGE REXTRAP AT ISOLDE



IN PRESENT EBIS CB CONCEPT,
TRAP IS THE LIMITATION (108 IONS/S)

REX-ISOLDE BUNCHING/COOLING/BREEDING

- * T_{COOLING}, T_{BREEDING} TIMES < 20 MS EACH
- * REPETITION RATE UP TO 100 HZ
- * $Q/A \sim 1/4.5$
- * MASS SEPARATOR (ACHROMATIC) RESOLUTION > 100
- © RAMP EBIS PLATFORM VOLTAGE -> DECOUPLE ISOL PART AND LINAC



1⁺ ions from ISOLDE

EFFICIENCIES (DESIGN VALUES)

• trap bunching: 90%

• beam transport: >85%

• EBIS injection: >50%

• EBIS $Q_i/\Sigma Q_i$: 30%

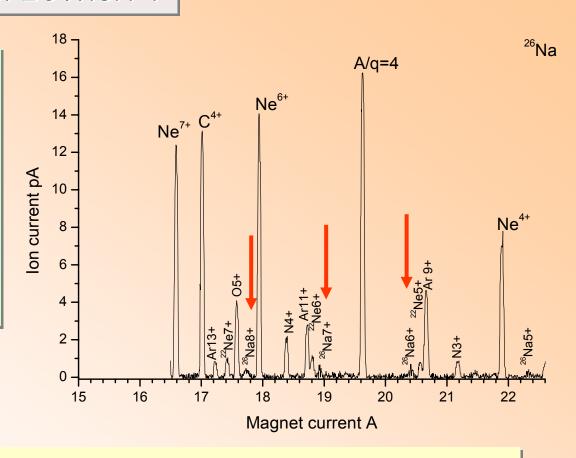
 $\rightarrow \Sigma_{\text{eff}}$ 12% in one charge state

PRICE FOR EBIS AND TRAP ~1.1 MUSD IN TOTAL

EXTRACTION MASS SPECTRUM I

LOW INTENSITY BEAMS

- * EBIS IS UHV (LOW RESIDUAL GAS, ~10-11 MBAR)
- Needs UHV conditions for OPERATION



EXAMPLE OF BEAM CONTAMINATION - LI RUN

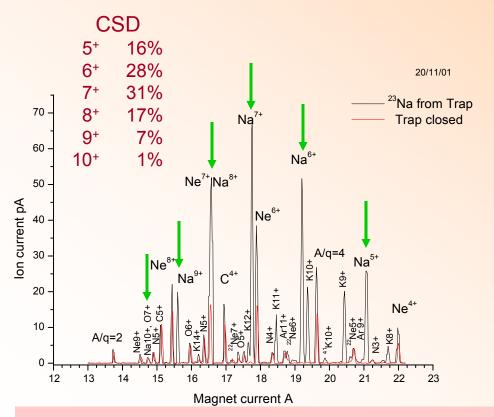
- * 9Li²⁺, run at A/q=4.5
- * Contamination of ¹⁸O⁴⁺ rest-gas of 1·10⁴ ions/s

- * Time gate =>
 - 15 times higher Li than O

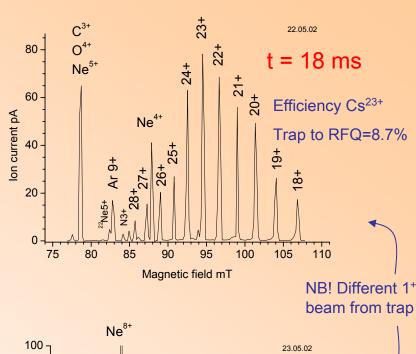
EXTRACTION MASS SPECTRUM |

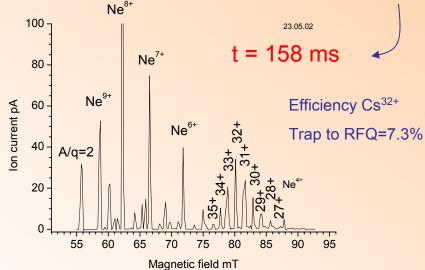
VARY BREEDING TIME

- * HIGHER INTENSITIES > 100 pA INJ.
- * LOWER EFFICIENCY BUT OVERALL MORE PARTICLES THROUGH



* STRONG NE CONTAMINATION FROM TRAP





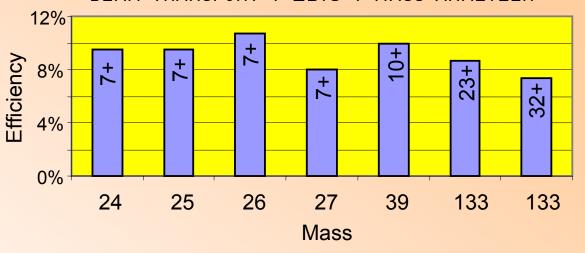
BREEDING EFFICIENCY

NB! PENNING TRAP
NOT INCLUDED!

EFFICIENCIES

BEAM TRANSPORT + EBIS + MASS ANALYZER

| CB IN STABLE | REXEBIS RADIOACTIVE |
|----------------------------------|-----------------------------------|
| 7Lj2+ | 9 Lj 2+ |
| ²³ Na ⁷⁺ | ²⁴⁻²⁹ Na ⁷⁺ |
| ²⁷ A 8+ | |
| ²⁴ Mg ⁸⁺ | ³⁰ Mg ⁸⁺ |
| 39 K 10+ | |
| | ¹³⁸ Ba ²⁶⁺ |
| ¹³³ Cs ³²⁺ | |
| | ¹⁵³ Sm ²⁸⁺ |



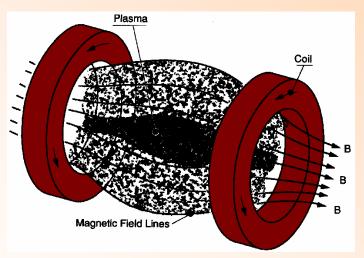
- **[☉] INDEPENDENT OF MASS**
- \odot CAN IN PRINCIPLE REACH ~30% (N⁷⁺ 30% & AR¹⁴⁺ 9.4% IN SACLAY AND STOCKHOLM)

EBIS DRAWBACKS AS CB

- © CATHODE LIMITED LIFETIME
- **⊗** COMPLICATED

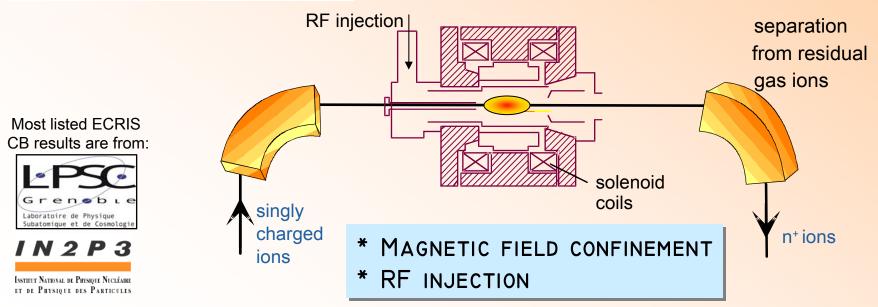
THE ECRIS CHARGE BREEDER

ELECTRON CYCLOTRON RESONANCE ION SOURCE



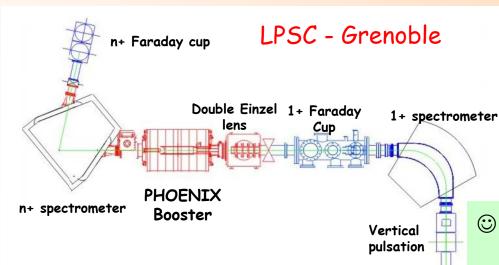
PRINCIPLE

- * INJECT VERY SLOW IONS THROUGH A PLASMA OF HOT e
- * ELECTRON ENERGY A FEW KEV
- * DENSITY <1.1013 S/CM3
- * IONIC CONFINEMENT $\tau_1 \sim 10$ MS TO A FEW 100 MS



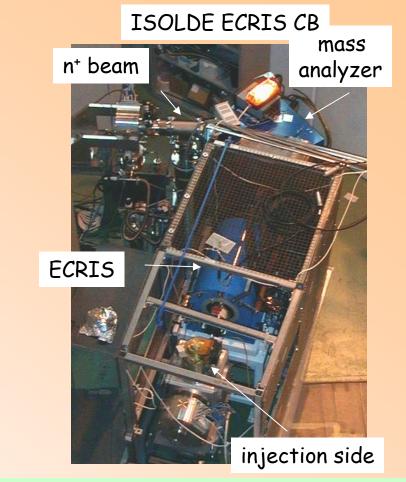
ECRIS AS CHARGE BREEDER

- ☺ I⁺ INJECTION CONTINUOUS OR BUNCHED
- Not so complex
- * CHARGE-TO-MASS RATIO OF <1/6



PRICE FOR PHOENIX AND RF GENERATOR ~300 KUSD

1+ source



- © ECRIS MAGNETS ON GROUND =>
 AVOID HV PLATFORM WITH 50 KW
- ⊗ INJECTION = EXTRACTION VOLTAGE =>
 - * VARY I + SOURCE POTENTIAL
 - * OR USE A VE-RFQ

ECRIS CHARACTERISTICS I

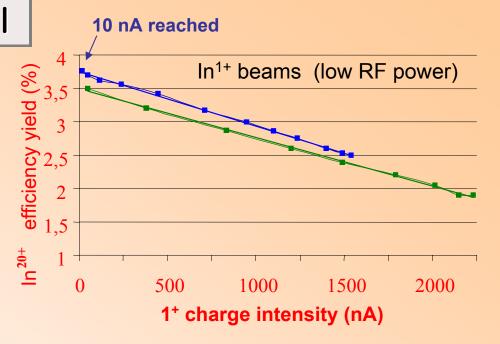
CONFINEMENT TIME

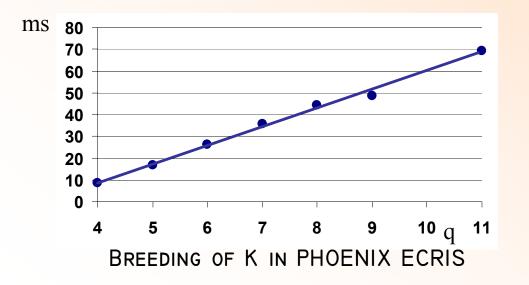
- * 10 MS PER CHARGE STATE
- * Breeding time ≠ Confinement time
- CHARGE TUNING WITH

RF POWER

MAGNETIC FIELD,

SUPPORT GAS PRESSURE



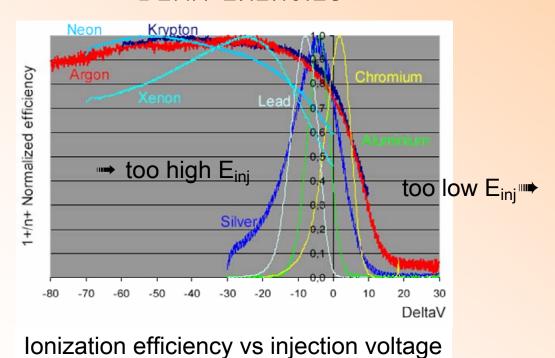


INTENSITY VS EFFICIENCY

- No PROBLEM WITH 10¹² IONS/S
- © ECRIS CAN ACCEPT >μA
- No efficiency decrease
 When decreasing the current

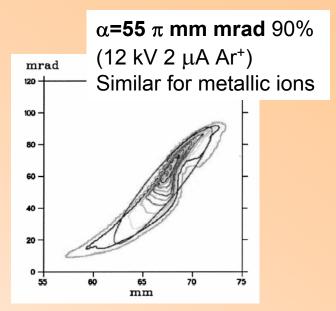
ECRIS CHARACTERISTICS II

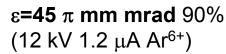
BEAM ENERGIES

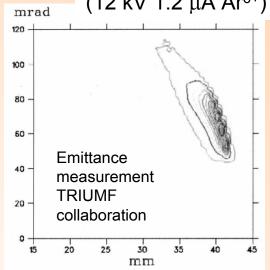


* EXTRACTED ENERGY SPREAD ~ I V * q

ACCEPTANCE / EMITTANCE

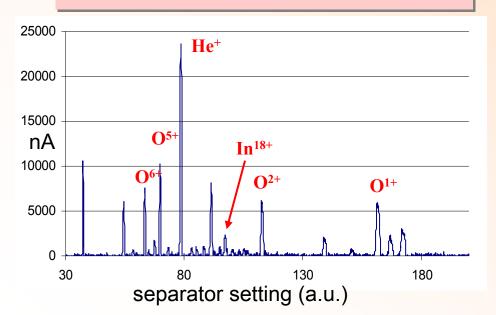


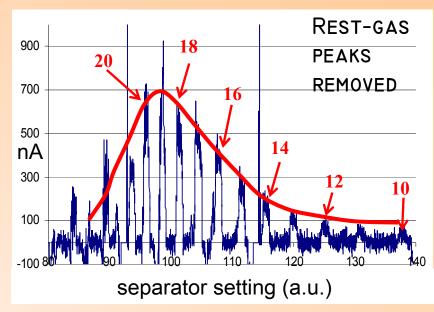




EXTRACTION MASS SPECTRUM

- * GLOBAL CAPTURE ~50% POSSIBLE (EXTRACTION IN TWO DIRECTIONS)
- * CSD BROAD DUE TO CONTINUOUS INJECTION





INJECTED BEAM: In⁺ 520 nA, 20 KeV RF power @ I4 GHz: 340 W

TOTAL HV CURRENT: 1.1 mA

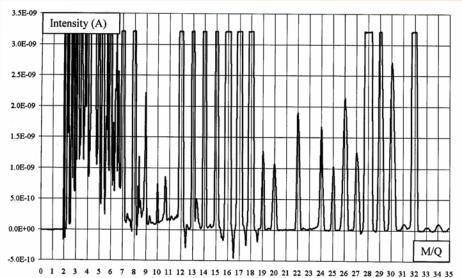
*
$$\eta(1^+ \rightarrow 18^+) = 6\%$$

* GLOBAL CAPTURE = 45%

RESIDUAL GAS BACKGROUND

- □ Total extracted current I-2 MA
- * WORKING PRESSURE = | TO | 10.10.6 MBAR
- * RESIDUAL GAS PEAKS >> RADIOACTIVE ATOMS

* Non UHV PHOENIX BOOSTER SPECTRUM, A/q=0-70

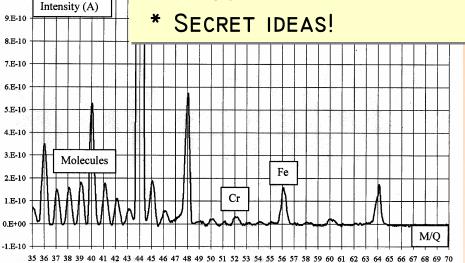


NOISE LEVEL IN BETWEEN RESIDUAL GAS PEAKS?

* KEK-JAERI HAS 10 NA IN 6<A/q<7

RESIDUAL GAS SUPPRESSION

- * WIEN FILTER
- * BAKEABLE UHV DEVICES?
- * MONOISOTOPIC BUFFER GAS
- * NEGs



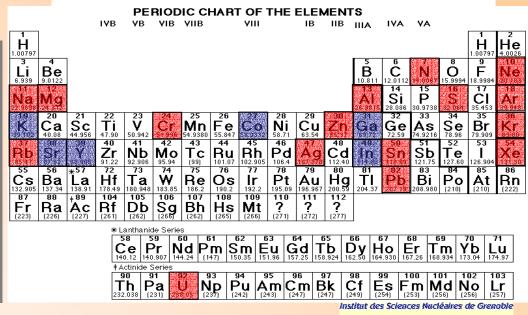
PRODUCED ELEMENTS

- © FAST SETUP: DIFFERENT
 STABLE BEAM WITHIN AN HOUR
- * EASIEST

 NOBLE GASES

 HEAVIER ELEMENTS

ELEMENTS WHICH HAVE BEEN EXPERIMENTALLY STUDIED WITH THE ISN-ECRIS CHARGE BREEDER





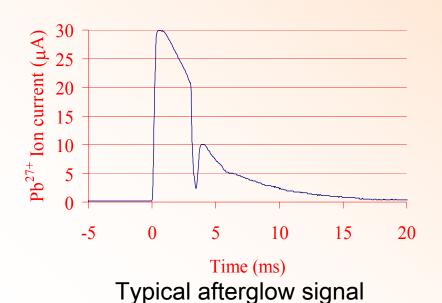
- * "DAILY PRODUCTION" OF A/q \approx 7
- * ELEMENTS PRODUCED IN ~10 DAYS:

¹¹⁵In, ¹⁰⁹Ag, ⁶⁴Zn, ¹²⁰Sn, ⁸⁸Sr, ⁶⁹Ga, ⁹⁰Y, ³⁹K, ⁸⁵Rb, ⁵⁹Co

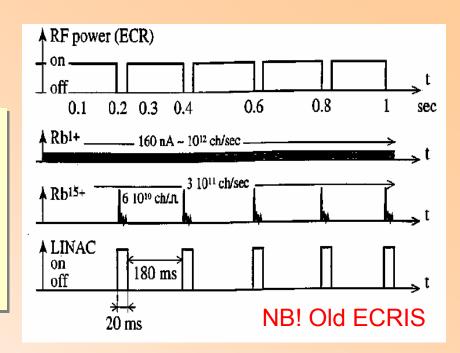
* CHARGE BREEDING EFFICIENCY OF AT LEAST 3%

PULSED EXTRACTION

- * EXTRACTION CW OR AFTERGLOW PULSED
- * AFTERGLOW METHOD = SWITCH OFF RF
- * PULSED EXTRACTION FOR SYNCHROTRONS AND PULSED LINACS



for charge bred Pb²⁷⁺

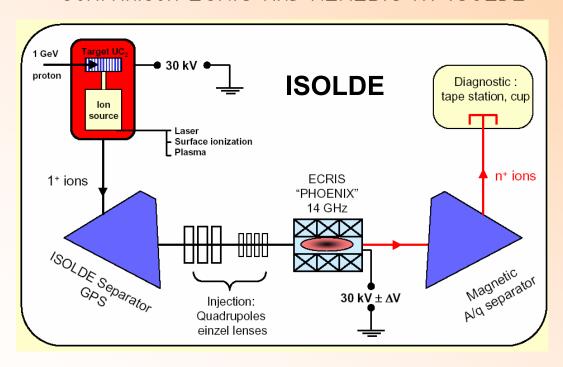


CB WITH AFTERGLOW EXTRACTION

- * BEAM IN RBI+
- * BEAM OUT RB¹⁵⁺
 6·10¹⁰ CHARGES/PULSE
 3·10¹¹ CHARGES/S
 - 2.2 % EFFICIENCY

ECRIS CBs around the world

COMPARISON ECRIS AND REXEBIS AT ISOLDE



- * FROM 10 TO 18 GHZ (28 GHZ POSSIBLE)
- * MODULAR AXIAL B-FIELD



RESULTS FROM KEK-JAERI

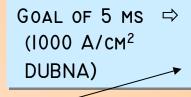
- * 18 GHz ECRIS, A/Q<7
- * 6.5% BREEDING EFFICIENCY XE+ TO XE²⁰⁺

* ISAC (TRIUMF) HAS ALSO A PHOENIX UNDER COMMISSIONING

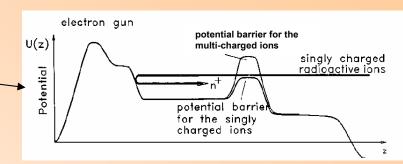
FUTURE EBIS

WHAT TO IMPROVE ON EBIS?

- I. SHORTENING OF THE TBREEDING
- 2. CONTINUOUS INJECTION —
- 3. INCREASED CHARGE CAPACITY



- * REPETITION RATE 200 HZ
- * NO LIFE-TIME LOSSES AT
- * HIGH CAPACITY



Continuous injection / Accu EBIS with RFQ cooler



Au³³⁺ A/q~6

40 ms breeding

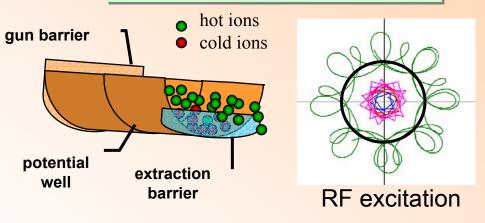
O1 x b) esind/seb 1.0

RHIC requirement scaled to EBTS trap length

Electron Current (A)

EBIS test stand

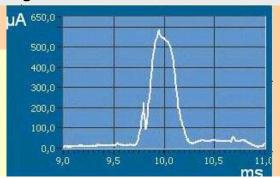
ADVANCED CHARGE BREEDING



TRENDS IN ECRIS DEVELOPMENT

- * SHORTER EXTRACTION PULSE
- * SHORTER CONFINEMENT TIME MODULAR ECRIS

PHOENIX 28 GHz high current extraction (Lead)



Shorter and higher afterglow

* Higher charge state / larger capacity / better I+ capture Higher RF frequency $n_e \propto \omega_{RF}^2 \; \text{(scaling rule)} \\ B_{\text{resonance}} \sim \omega_{RF} \; \text{-> high B-field and sc solenoids}$

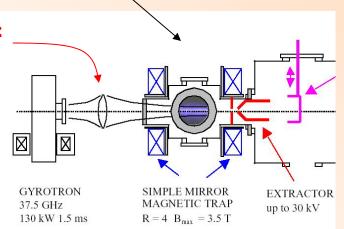
Optical coupling of the UHF power:

* < 100 KW / 1 ms each 20 s

* ω_{RF} = 37.5 *GHz*

Very simple magnetic system

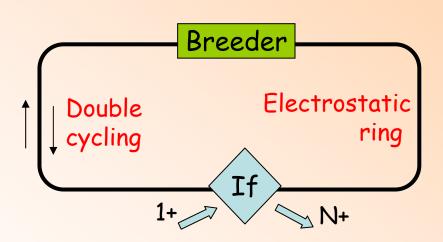
IAP Nizhny Novgorod + LPSC





 $n_e \sim 5.10^{13} \text{ cm}^{-3}$

BREEDER RING

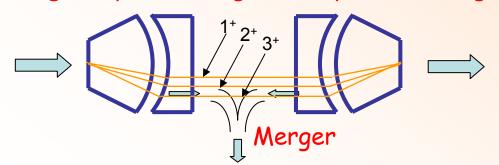


OPERATION EFFICIENCY

 I_{∞} = na/[1- μ (1-a)] NB! Decay n=extraction eff. losses a=ionisation eff. excluded. μ =ring transport eff.

Example: n=0.9, a=0.8, $\mu=0.9 => 0.87$

Large dispersive magnetic separator/merger



PROBLEMS

- * ADDED DELAY TIME
- * TRANSPORT LOSSES
- * EXTRACTION/INJECTION LOSSES

Idea from E. A. Lamzin, Russia Pursued by A. Villari and GANIL

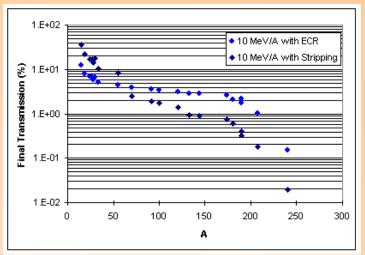
| | 1 | | Stripper | EBIS | ECRIS |
|-----------------------------------------------|---|-----------------------|--------------------------------------------|------------------------------------|----------------------------------|
| irence | | Simplicity | 3, passive element | 1, complicated (SC, UHV, e-gun) | 2, medium (RF, beam tuning) |
| | | Beam properties in | 3, no special requirements | 1, bunched, small acceptance | 2, CW, medium acceptance |
| | | Beam properties out | 1, emittance blow-up | 3, us or ms bunch, small emittance | 2, CW or bunched |
| ב ב ב | | Low intensities | 3, no contamination | 2, some 100 fA | 1, high rest-gas level |
| 5 5 | | Rapidity | 3, instant, us isotopes | 2, 10 ms | 1, a few 10 ms |
| weight function according personal preference | | CSD | 3, narrow, high charge state | 3, narrow, high charge state | 2, broad CSD, moderate charge |
| | | CSD tuning | 1, not tunable | 3, change time | 2, many parameters |
| | | Machine contamination | 2, foil change | 1, multiple parts | 2, change plasma liner |
| uncti | | Storage time | 1, non existing | 3, up to s | 2, ~100 ms |
| | | Beam capacity | 3, very high, 100 uA | 1, limited to nA | 2, several uA |
| D > | | Energy spread | 1, ∆W/W~1‰ | 2, a few 10 eV*q | 3, some eV*q |
| | | Efficiency | 2, a few % | 2, a few % | 2, a few % |
| | | Life-time | 2, foil breakage, 50 mC/cm ² | 1, electron cathode | 3, klystron lifetime |
| | | Price | 1 high, (incl. pre-acc) | 2 ~1 MUSD (trap +EBIS) | 3, ~0.3 MUSD |

CONCLUSIONS

GUIDELINES

- * OBTAINED CB EFFICIENCIES IN 5% REGION
- * EBIS FOR LOW INTENSITIES
- * ECRIS-STRIPPER COMBINATION FOR HIGH INTENSITIES

BREAKING POINT I NA



Transmission efficiencies for ECR and stripping schemes

THREE CHOICES - THREE VIRTUES

Stripper



Fast but expensive (pre-acc. LINAC)

ECRIS



Large capacity but dirty

EBIS



Electrical car

Clean but low capacity

* FUTURE INTERESTING CONCEPTS

* ADVANCED CHARGE BREEDING PROPOSAL

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